# MOTOROLA28供应商 SEMICONDUCTOR TECHNICAL DATA

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| Amplifier Transis  | Stor                    |                    |                               |          | MP               | S642             | 28  |
|--|-------------------------|--------------------|-------------------------------|----------|------------------|------------------|-----|
| MAXIMUM RATINGS  |                         | 2                  | DLLECTOR<br>3<br>1<br>EMITTER | F        | 1 <sup>4</sup> 2 | 3<br>29–04, STYL | E1  |
| Rating   | Symbol                  | Value              | Unit                          | 1        |                  | 2 (TO-226A       |     |
| Collector-Emitter Voltage  | V <sub>CEO</sub>        | 50                 | Vdc                           | 100      | 31               | Page C           | 214 |
| Collector-Base Voltage   | VCEO<br>VCBO            | 60                 | Vdc                           | 125- 10  | WW.P             |                  |     |
| Emitter-Base Voltage   | V <sub>EBO</sub>        | 6.0                | Vdc                           | 1        |                  |                  |     |
| Collector Current — Continuous   | IC                      | 200                | mAdc                          |          |                  |                  |     |
| Total Device Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C                    | PD                      | 625<br>5.0         | mW<br>mW/°C                   |          |                  |                  |     |
| Total Device Dissipation @ T <sub>C</sub> = 25°C<br>Derate above 25°C                    | PD                      | 1.5<br>12          | Watts<br>mW/°C                |          |                  |                  |     |
| Operating and Storage Junction<br>Temperature Range                                      | TJ, Tstg                | -55 to +150        | °C                            |          |                  |                  |     |
| HERMAL CHARACTERISTICS   |                         |                    |                               | - E      |                  |                  |     |
| Characteristic   | Symbol                  | Max                | Unit                          | CE W     |                  |                  |     |
| Thermal Resistance, Junction to Ambient  | R <sub>0JA</sub>        | 200                | °C/W                          |          |                  |                  |     |
| Thermal Resistance, Junction to Case   | R <sub>0</sub> JC       | 83.3               | °C/W                          |          |                  |                  |     |
| ELECTRICAL CHARACTERISTICS (T,   | $a = 25^{\circ}C$ unles | ss otherwise noted | )                             |          |                  |                  |     |
| Chara  | cteristic               |                    |                               | Symbol   | Min              | Max              | Un  |
| OFF CHARACTERISTICS  |                         |                    |                               |          |                  |                  |     |
| Collector – Emitter Breakdown Voltage<br>(I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0) |                         |                    |                               | V(BR)CEO | 50               | 510              | Vd  |
| Collector-Base Breakdown Voltage<br>(I <sub>C</sub> = 0.1 mAdc, I <sub>E</sub> = 0)      |                         |                    |                               | V(BR)CBO | 60               | 2.50.0           | Vd  |
| Collector Cutoff Current<br>(V <sub>CE</sub> = 30 Vdc)                                   |                         |                    |                               | ICES     |                  | 0.025            | μΑ  |
| Collector Cutoff Current<br>(V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)               |                         |                    |                               | ICBO     | _                | 0.01             | μΑ  |
| Emitter Cutoff Current $(V_{EB} = 5.0 \text{ Vdc}, I_C = 0)$                             |                         |                    |                               | IEBO     | _                | 0.01             | μΑ  |





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**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted) (Continued)

| Characteristic  | Symbol           | Min                      | Max             | Unit   |
|---|------------------|--------------------------|-----------------|--------|
| ON CHARACTERISTICS  | •                |                          | •               | •      |
| DC Current Gain<br>$(V_{CE} = 5.0 \text{ Vdc}, I_{C} = 0.01 \text{ mAdc})$<br>$(V_{CE} = 5.0 \text{ Vdc}, I_{C} = 0.1 \text{ mAdc})$<br>$(V_{CE} = 5.0 \text{ Vdc}, I_{C} = 1.0 \text{ mAdc})$<br>$(V_{CE} = 5.0 \text{ Vdc}, I_{C} = 10 \text{ mAdc})$ | hfe              | 250<br>250<br>250<br>250 | <br>650<br><br> |        |
| Collector–Emitter Saturation Voltage<br>( $I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$ )<br>( $I_C = 100 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$ )   | VCE(sat)         |                          | 0.2<br>0.6      | Vdc    |
| Base-Emitter On Voltage<br>(I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 5.0 Vdc)   | VBE(on)          | 0.56                     | 0.66            | Vdc    |
| SMALL-SIGNAL CHARACTERISTICS  |                  |                          | -               | -      |
| Current–Gain — Bandwidth Product<br>(I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 5.0 V, f = 100 MHz)   | fT               | 100                      | 700             | MHz    |
| Output Capacitance<br>( $V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )   | C <sub>obo</sub> | _                        | 3.0             | pF     |
| Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz}$ )  | C <sub>ibo</sub> |                          | 8.0             | pF     |
| Input Impedance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , f = 1.0 kHz)  | h <sub>ie</sub>  | 3.0                      | 30              | kΩ     |
| Voltage Feedback Ratio ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , f = 1.0 kHz)   | h <sub>re</sub>  | 2.0                      | 20              | X 10-4 |
| Small–Signal Current Gain ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , f = 1.0 kHz)  | h <sub>fe</sub>  | 200                      | 800             | -      |
| Output Admittance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , f = 1.0 kHz)  | h <sub>oe</sub>  | 5.0                      | 50              | μmhos  |

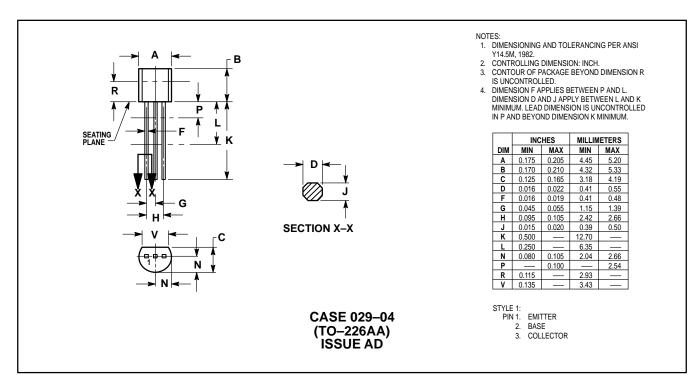
## NOISE FIGURE/TOTAL NOISE VOLTAGE CHARACTERISTICS

|   | NF<br>Max | VT<br>(1) | NF<br>Max | VT<br>(2) | NF<br>Max | VT<br>(3) | Ur | nit |
|---|-----------|-----------|-----------|-----------|-----------|-----------|----|-----|
| Noise Figure/Voltage ( $V_{CE} = 5.0 \text{ V}, I_C = 0.1 \text{ mA}, T_A = 25^{\circ}\text{C}$ ) | 7.0       | 18.1      | 6.0       | 5700      | 3.5       | 4.3       | dB | nV  |

1.  $R_S = 10 \text{ k}\Omega$ , BW = 1.0 Hz, f = 100 Hz2.  $R_S = 50 \text{ k}\Omega$ , BW = 15.7 kHz, f = 10 Hz–10 kHz 3.  $R_S = 500 \Omega$ , BW = 1.0 Hz, f = 10 Hz

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### PACKAGE DIMENSIONS



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